

### **INCHANGE SEMICONDUCTOR**

## **isc Silicon NPN Power Transistor**

# S2000

#### DESCRIPTION

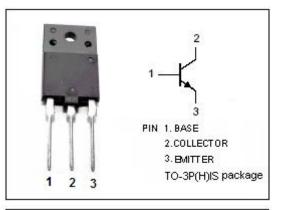
- · High Breakdown Voltage-
- : V<sub>CBO</sub>= 1500V (Min)
- High Switching Speed
- Low Saturation Voltage
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

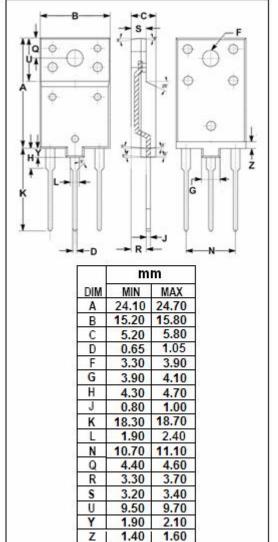
#### **APPLICATIONS**

- · Color TV horizontal output applications
- · Color TV switching regulator applications

### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	1500	V
V <sub>CEO</sub>	Collector-Emitter Voltage	700	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
lc	Collector Current	8	A
Ісм	Collector Current-peak	15	A
Ів	Base Current	4	A
Pc	Collector Power Dissipation @ T <sub>C</sub> =25°C	125	W
TJ	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C





isc website: <u>www.iscsemi.com</u>

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### **ELECTRICAL CHARACTERISTICS**

 $T_{\text{C}}\text{=}25^{\circ}\!\!\!^{\circ}\!\!^{\circ}\!\!^{\circ}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
Vceo(sus)	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 50mA ; I <sub>B</sub> = 0	700			v
V(BR)EBO	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 1mA ;I <sub>C</sub> = 0	5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 4.5A ;I <sub>B</sub> = 1.0A			5.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 4.5A ;I <sub>B</sub> = 1.0A			1.2	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 1500V; V <sub>BE</sub> = 0			1	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 1A ; V <sub>CE</sub> = 5V	10		30	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 4.5A ; V <sub>CE</sub> = 5V	4.5		9	
Сов	Output Capacitance	I <sub>E</sub> = 0 ; V <sub>CB</sub> = 10V;f= 1MHz		200		pF
f⊤	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.1A ; V <sub>CE</sub> = 10V	2			MHz

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